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				Application Number	08/781,920
				Filing Date	December 30, 1996
				First Named Inventor	Takeshi FUKUNAGA et al.
				Group Art Unit	1762
				Examiner Name	M. PADGETT
Sheet	1	of	1	Attorney Docket Number	740756-1614

U.S. PATENT DOCUMENTS						
Examiner Initials ⁵	Cite No. ¹	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number	Kind Code ² (if known)			
MJP		5,619,044		Makita et al.	Apr. 8, 1997	COPY OF PAPERS ORIGINALLY FILED
		5,696,003		Makita et al.	Dec. 9, 1997	
		5,821,562		Makita et al.	Oct. 13, 1998	
		5,837,569		Makita et al.	Nov. 17, 1998	

FOREIGN PATENT DOCUMENTS								
Examiner Initials ⁵	Cite No. ¹	Foreign Patent Document			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		Office ³	Number ⁴	Kind Code ² (if known)				
MJP			7-283135		Sharp Corp.	Oct. 27, 1995	US 5,419,044	Abstract
			8-8181		Sharp Corp.	Jan. 12, 1996	US PN 5,446,003	Abstract

OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ⁵	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
MJP		KAWAZU et al., "Low-Temperature Crystallization of Hydrogenated Amorphous Silicon Induced by Nickel Silicide Formation", Japanese Journal of Applied Physics, Vol. 29, No. 12, Dec. 1990, pp 2698-2704.	

Examiner Signature	<i>M. Padgett</i>	Date Considered	4/22/02
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¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

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